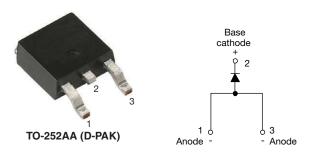


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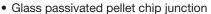
Vishay Semiconductors

## Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



PRODUCT SUMMARY							
Package	TO-252AA (D-PAK)						
I <sub>F(AV)</sub>	8 A						
V <sub>R</sub>	200 V, 400 V, 600 V						
V <sub>F</sub> at I <sub>F</sub>	1.2 V						
I <sub>FSM</sub>	150 A						
t <sub>rr</sub>	55 ns						
T <sub>J</sub> max.	150 °C						
Diode variation	Single die						
Snap factor	0.5						

#### **FEATURES**







RoHS

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

#### **DESCRIPTION**

The VS-8EWF..SPbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This series is designed and qualified for industrial level.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	VALUES	UNITS							
I <sub>F(AV)</sub>	Sinusoidal waveform	8	А						
V <sub>RRM</sub>		200 to 600	V						
I <sub>FSM</sub>		150	А						
V <sub>F</sub>	8 A, T <sub>J</sub> = 25 °C	1.2	V						
t <sub>rr</sub>	1 A, 100 A/µs	55	ns						
T <sub>J</sub>	Range	-40 to +150	°C						

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-8EWF02SPbF	200	300							
VS-8EWF04SPbF	400	500	3						
VS-8EWF06SPbF	600	700							

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 96 °C, 180° conduction half sine wave	8					
Maximum peak one cycle	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied 125		Α				
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	ms sine pulse, no voltage reapplied 150					
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied 78		- A <sup>2</sup> s				
Maximum 1-t for fusing		10 ms sine pulse, no voltage reapplied 110						
Maximum I²√t for fusing I²√t		t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s				

# **VS-8EWF..SPbF Soft Recovery Series**

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ELECTRICAL SPECIFICATIONS								
PARAMETER	VALUES	UNITS						
Maximum forward voltage drop	$V_{FM}$	8 A, T <sub>J</sub> = 25 °C	1.2	V				
Forward slope resistance	r <sub>t</sub>	T <sub>.1</sub> = 150 °C	16	mΩ				
Threshold voltage	V <sub>F(TO)</sub>	1) = 150 C	1.13	V				
Maximum reverse leakage current		T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	0.1	mA			
iviaximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 150 °C	VR = nated VRRM	3				

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •				
Reverse recovery time	t <sub>rr</sub>	I <sub>σ</sub> at 8 Δ .	200	ns	I <sub>FM</sub> +				
Reverse recovery current	I <sub>rr</sub>	- I <sub>F</sub> at 8 A <sub>pk</sub> 25 Α/μs	2.6	А	t <sub>a</sub>   t <sub>b</sub>				
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	0.25	μC	di di Q,,				
Snap factor	S		0.5		dt $I_{rr}$				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS							
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C				
Maximum thermal resistance, junction to case RthJ0		DC operation	2.5	°C/W				
Typical thermal resistance, junction to ambient (PCB mount)			50	C/VV				
Approximate weight			1	g				
Approximate weight			0.03	oz.				
Marking device		Case style TO-252AA (D-PAK)	8EWI	-06S				

#### Note

<sup>(1)</sup> When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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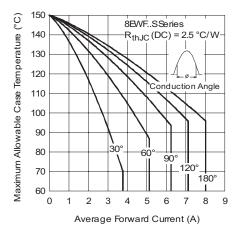


Fig. 1 - Current Rating Characteristics

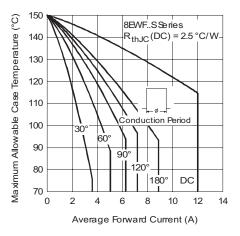


Fig. 2 - Current Rating Characteristics

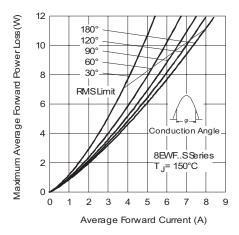


Fig. 3 - Forward Power Loss Characteristics

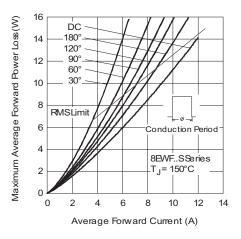


Fig. 4 - Forward Power Loss Characteristics

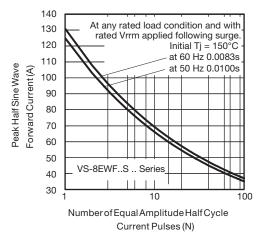


Fig. 5 - Maximum Non-Repetitive Surge Current

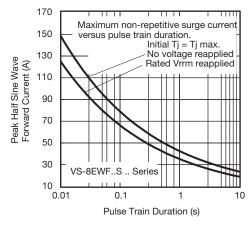


Fig. 6 - Maximum Non-Repetitive Surge Current

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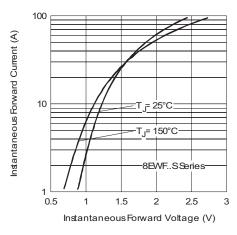


Fig. 7 - Forward Voltage Drop Characteristics

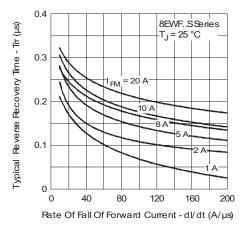


Fig. 8 - Recovery Time Characteristics,  $T_J = 25$  °C

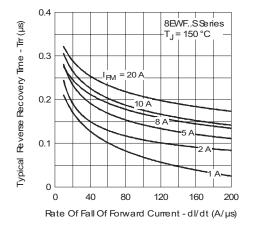


Fig. 9 - Recovery Time Characteristics, T<sub>J</sub> = 150 °C

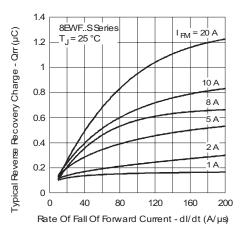


Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C

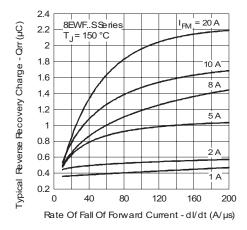


Fig. 11 - Recovery Charge Characteristics,  $T_J = 150 \, ^{\circ}\text{C}$ 

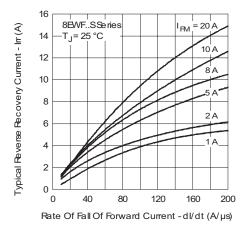


Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

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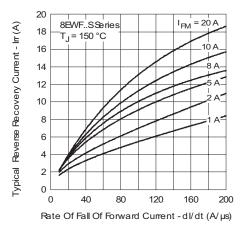


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

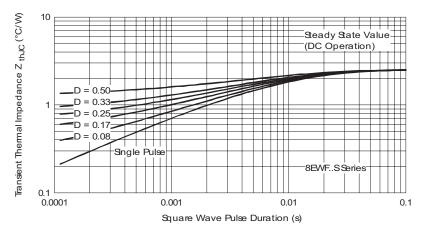


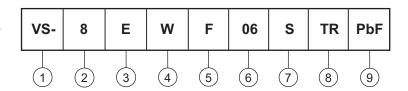
Fig. 14 - Thermal Impedance  $Z_{thJC}$  Characteristics

## **VS-8EWF..SPbF Soft Recovery Series**

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### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (8 = 8 A)

3 - Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

F = fast soft recovery rectifier

02 = 200 V 04 = 400 V

6 - Voltage code x 100 = V<sub>RRM</sub>

06 = 600 V

7 - S = surface mountable

TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

9 - PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95551						



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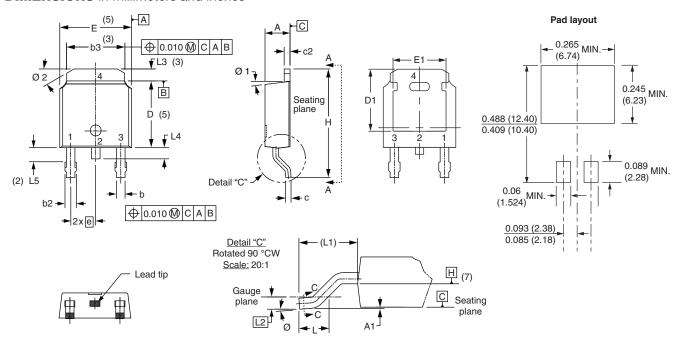
**NOTES** 

3

2

## **D-PAK (TO-252AA)**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES			SYMBOL	MILLIN	IETERS	INC	HES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	:5	STIVIBUL	MIN.	MAX.	MIN.	MAX.
Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060
D1	5.21	-	0.205	1	3		Ø	0°	10°	0°	10°
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°

### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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